

**IN THE CLAIMS**

1. (Previously Presented) A mask-making member comprising:

a plurality of pattern formation regions in which mask circuit patterns are to be formed;

and

a supporting region in which any mask circuit pattern is not to be formed, said supporting region being provided for holding said plurality of pattern formation regions while separating said plurality of pattern formation regions from each other;

wherein said supporting region has first alignment marks used at the time of exposure of a mask made from said mask-making member for forming said mask circuit patterns thereon, and second alignment marks used at the time of exposure of a substrate to be exposed for forming circuit patterns thereon, wherein said first and second alignment marks are formed on a common surface of said supporting region.

2. (Original) A mask-making member according to claim 1, wherein said first

alignment marks are formed in such a manner that one or more of said first alignment marks are located in a portion, around each of said plurality of pattern formation regions, of said supporting region, and said second alignment marks are formed in such a manner as to be all located in a portion, outside an area formed by said plurality of said pattern formation regions, of said supporting region.

3. (Original) A mask-making member according to claim 1, wherein shapes of said

first alignment marks are different from those of said second alignment marks.

4. (Original) A mask-making member according to claim 1, wherein said mask-

making member is a transmission mask-making member.

5. (Original) A mask-making member according to claim 1, wherein said mask-making member is a stencil mask-making member.

6. (Original) A mask-making member according to claim 4, wherein said first alignment marks and said second alignment marks are formed on an electron scatterer formed on a membrane.

7. (Original) A mask-making member according to claim 4, wherein said first alignment marks and said second alignment marks are formed on an electron scatterer formed on a membrane by selectively removing said electron scatterer.

8. (Original) A mask-making member according to claim 5, wherein said first alignment marks and said second alignment marks are formed on a mask board.

9. (Original) A mask-making member according to claim 5, wherein said first alignment marks and said second alignment marks are formed on a mask board by selectively removing said mask board.

10. (Original) A mask-making member according to claim 5, wherein said first alignment marks and said second alignment marks are formed on a mask board by selectively removing said mask board to form holes or grooves in said mask board, and burying said holes or grooves in said mask board, and burying said holes or grooves with a metal whose atoms have atomic weights heavier than those of atoms of said mask board.

11. (Original) A mask-making member according to claim 10, wherein said metal is platinum, gold, silver, copper, tungsten, tantalum, or molybdenum.

Claims 12-38 (Cancelled)

39. (Original) A mask comprising:

a plurality of pattern formation regions in which mask circuit patterns are formed; and  
a supporting region in which any mask circuit pattern is not formed, said supporting  
region being provided for holding said plurality of pattern formation regions while separating  
said plurality of pattern formation regions from each other;  
wherein said supporting region has first alignment marks used at the time of exposure of  
said mask for forming said mask circuit patterns thereon, and second alignment marks used at the  
time of exposure of a substrate to be exposed for forming circuit patterns thereon.

40. (Original) A mask according to claim 39, wherein said first alignment marks are  
formed in such a manner that one or more of said first alignment marks are located in a portion,  
around each of said plurality of pattern formation regions, of said supporting region, and said  
second alignment marks are formed in such a manner as to be all located in a portion, outside an  
area formed by said plurality of said pattern formation regions, of said supporting region.

41. (Original) A mask according to claim 39, wherein shapes of said first alignment  
marks are different from those of said second alignment marks.

42. (Original) A mask according to claim 39, wherein said mask is a transmission  
mask.

43. (Original) A mask according to claim 39, wherein said mask is a stencil mask.

44. (Original) A mask according to claim 42, wherein said first alignment marks and said second alignment marks are formed on an electron scatterer formed on a membrane.

45. (Original) A mask according to claim 42, wherein said first alignment marks and said second alignment marks are formed on an electron scatterer formed on a membrane by selectively removing said electron scatterer.

46. (Original) A mask according to claim 43, wherein said first alignment marks and said second alignment marks are formed on a mask board.

47. (Original) A mask according to claim 43, wherein said first alignment marks and said second alignment marks are formed on a mask board by selectively removing said mask board.

48. (Original) A mask according to claim 43, wherein said first alignment marks and said second alignment marks are formed on a mask board by selectively removing said mask board to form holes or grooves in said mask board, and burying said holes or grooves with a metal whose atoms have atomic weights heavier than those of atoms of said mask board.

49. (Original) A mask according to claim 48, wherein said metal is platinum, gold, silver, copper, tungsten, tantalum, or molybdenum.

Claims 50-86 (Cancelled)

87. (Previously Presented) A mask-making member comprising:  
a plurality of pattern formation regions in which mask circuit patterns are to be formed;

and

a supporting region in which any mask circuit pattern is not to be formed, said supporting region being provided for holding said plurality of pattern formation regions while separating said plurality of pattern formation regions from each other;

wherein said supporting region has first alignment marks used at the time of exposure of a mask made from said mask-making member for forming said mask circuit patterns thereon, and second alignment marks used at the time of exposure of a substrate to be exposed for forming circuit patterns thereon, wherein said second alignment marks comprises a pattern formed from a plurality of lines with spaces between said lines.

88. (Previously Presented) A mask-making member according to claim 1, wherein a stepped position of said first mark is buried with platinum, gold, silver, copper, tungsten, tantalum, or molybdenum.

89. (Previously Presented) A mask-making member according to claim 1, wherein said second mark is formed outside an area formed by all regions on which mask circuit pattern is to be formed.